

P-Channel 20 V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)	Q _g (Typ.)		
- 20	0.184 at V _{GS} = - 4.5 V	- 0.94	4.23		
- 20	0.268 at V _{GS} = - 2.5 V	- 0.78	4.23		

FEATURES

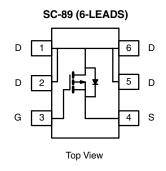
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFET
- 100 % R_g Tested
- Compliant to RoHS Directive 2002/95/EC

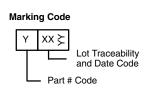


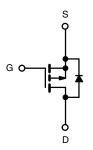
ROHS COMPLIANT HALOGEN FREE

APPLICATIONS

• Load Switch for Portable Devices







Ordering Information: Si1069X-T1-GE3 (Lead (Pb)-free and Halogen-free)

P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)						
Parameter	Symbol	Limit	Unit			
Drain-Source Voltage	V _{DS}	- 20	V			
Gate-Source Voltage		V _{GS}	± 12			
Continuous Drain Current (T _{.1} = 150 °C)	T _A = 25 °C	1-	- 0.94 ^{b, c}			
Continuous Diain Current (1) = 150°C)	T _A = 70 °C	l ID	- 0.75 ^{b, c}	Α Α		
Pulsed Drain Current		I _{DM} - 8		^		
Continuous Source-Drain Diode Current T _A = 25 °C		I _S	- 0.2 ^{b, c}			
Mariana Barra Biraira kand	T _A = 25 °C	PD	0.236 ^{b, c}	w		
Maximum Power Dissipation ^a	T _A = 70 °C] ' D	0.151 ^{b, c}	VV		
Operating Junction and Storage Temperature Rai	T _J , T _{stg}	- 55 to 150	°C			

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Typical	Maximum	Unit		
Marrian III de Ambrianta h	t ≤ 5 s	B	440	530	°C/W	
Maximum Junction-to-Ambient ^{a, b}	Steady State	R_{thJA}	540	650	C/VV	

Notes:

- a. Based on $T_A = 25$ °C.
- b. Surface mounted on 1" x 1" FR4 board.
- c. t = 5 s.

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Parameter	Symbol Test Conditions		Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	- 20			V	
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	I _D = - 250 μA		- 16.7		\//0C	
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	η = - 250 μΑ		2.95		mV/°C	
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 0.6		- 1.5	V	
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$			± 100	nA	
Zava Cata Valtaga Drain Current	I	V _{DS} = - 20 V, V _{GS} = 0 V			- 1	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 20 V, V _{GS} = 0 V, T _J = 85 °C			- 10	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = \ge 5 \text{ V}, V_{GS} = -4.5 \text{ V}$	- 8			Α	
Dunia Comman Con Cit is 5	_	V _{GS} = - 4.5 V, I _D = - 0.94 A		0.153	0.184	_	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 2.5 V, I _D = - 0.78 A		0.218	0.268	Ω	
Forward Transconductance	9 _{fs}	V _{DS} = - 10 V, I _D = - 0.94 A		4		S	
Dynamic ^b					•	•	
Input Capacitance	C _{iss}			308			
Output Capacitance	C _{oss}	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		78		pF	
Reverse Transfer Capacitance	C _{rss}			59			
Total Cata Charge	0	$V_{DS} = -10 \text{ V}, V_{GS} = -5 \text{ V}, I_{D} = -0.94 \text{ A}$		4.57	6.86		
Total Gate Charge	Q_g			4.23	6.35	nC	
Gate-Source Charge	Q_{gs}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -0.94 \text{ A}$		0.71			
Gate-Drain Charge	Q _{gd}			1.67		1	
Gate Resistance	R _g	f = 1 MHz		9	13.5	Ω	
Turn-On Delay Time	t _{d(on)}			19	28.5		
Rise Time	t _r	V_{DD} = - 10 V, R_{L} = 13.3 Ω		31	47	1	
Turn-Off DelayTime	t _{d(off)}	$I_D \cong -0.75 \text{ A}, V_{GEN} = -4.5 \text{ V}, R_g = 1 \Omega$		23	34.5	ns	
Fall Time	t _f			7	10.5	1	
Drain-Source Body Diode Characteris	stics			l		ı	
Pulse Diode Forward Current ^a	I _{SM}				8	Α	
Body Diode Voltage	V _{SD}	I _S = - 0.64 A		- 0.8	- 1.2	V	
Body Diode Reverse Recovery Time	t _{rr}			19	28.5	nC	
Body Diode Reverse Recovery Charge	Q _{rr}	0.04 A 21/24 400 A/22		6.65	10		
Reverse Recovery Fall Time	t _a	I _F = - 0.64 A, dl/dt = 100 A/μs		7		ns	
Reverse Recovery Rise Time t _b				12		1	

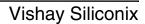
Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

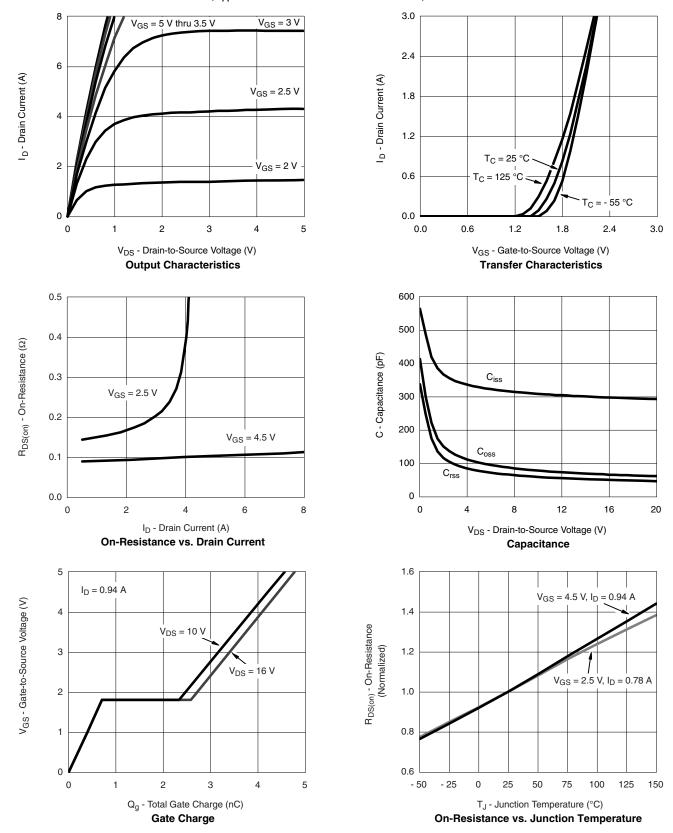
b. Guaranteed by design, not subject to production testing.







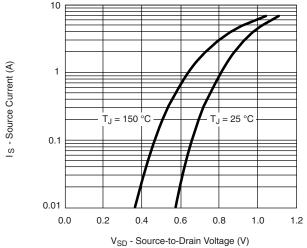
TYPICAL CHARACTERISTICS ($T_A = 25$ °C, unless otherwise noted)



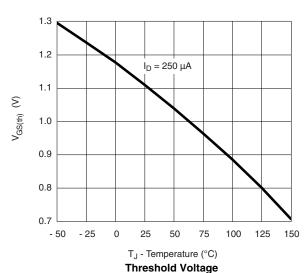
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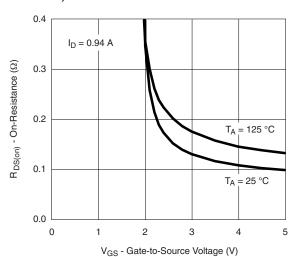
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TYPICAL CHARACTERISTICS ($T_A = 25$ °C, unless otherwise noted)

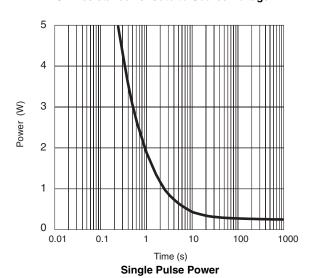


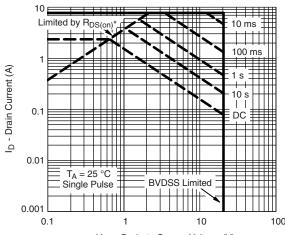
Source-Drain Diode Forward Voltage





On-Resistance vs. Gate-to-Source Voltage





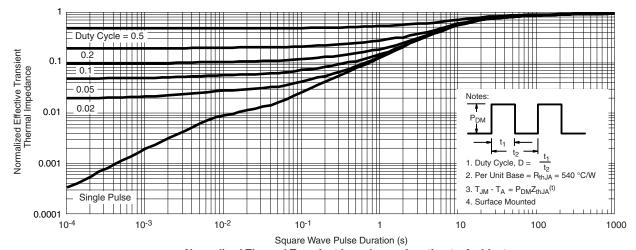
 $V_{DS} \mbox{ - Drain-to-Source Voltage (V)} \\ ^* \mbox{ V}_{GS} \mbox{ > minimum V}_{GS} \mbox{ at which } R_{DS(on)} \mbox{ is specified}$

Safe Operating Area, Junction-to-Ambient





TYPICAL CHARACTERISTICS ($T_A = 25$ °C, unless otherwise noted)

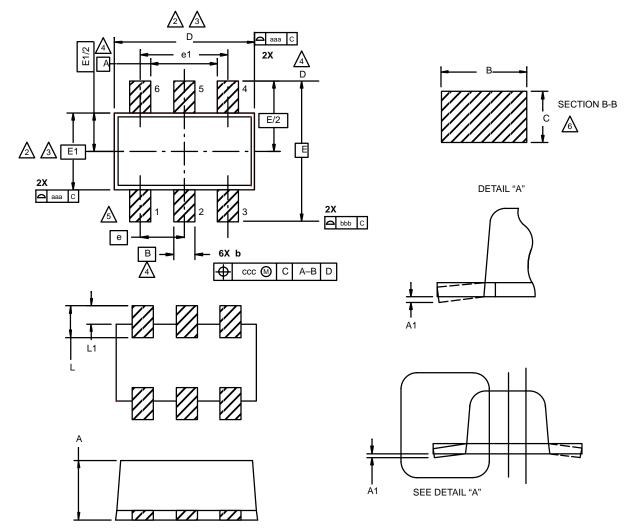


Normalized Thermal Transient Impedance, Junction-to-Ambient

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?70442.



SC89: 6- LEADS (SOT-563F)



NOTES:

1. Dimensions in millimeters.



Dimension D does not include mold flash, protrusions or gate burrs. Mold flush, protrusions or gate burrs shall not exceed 0.15 mm per dimension E1 does not include interlead flash or protrusion, interlead flash or protrusion shall not exceed 0.15 mm per side.



Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, the bar burrs, gate burrs and interlead flash, but including any mismatch between the top and the bottom of the plastic body.



Datums A, B and D to be determined 0.10 mm from the lead tip.



Terminal numbers are shown for reference only.



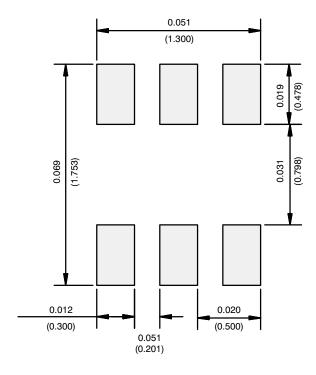
These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.

	MILLIM	IETERS			Tolerances Of Form And	
Dim	Min	Max	Note	Symbol	Position	
Α	0.56	0.60		aaa	0.10	
A1	0.00	0.10		bbb	0.10	
b	0.15	0.30		ccc	0.10	
С	0.10	0.18				
D	1.50	1.70	2, 3			
E	1.55	1.70				
E1	1.20 BSC		2, 3			
е	0.50 BSC					
e1	1.00 BSC					
L	0.35 BSC					
L1	0.20 BSC					
ECN: E-00499—Rev. B, 02-Jul-01						

DWG: 5880



RECOMMENDED MINIMUM PADS FOR SC-89: 6-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

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